

## **INCHANGE SEMICONDUCTOR**

# isc N-Channel Mosfet Transistor

## 12N60

## FEATURES

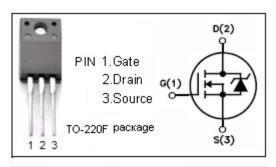
- Drain Current –I\_D= 12A@ T\_C=25 $^\circ\!\!\!\mathrm{C}$
- Drain Source Voltage-
- : V<sub>DSS</sub>= 600V (Min)
- Static Drain-Source On-Resistance
- : R<sub>DS(on)</sub> = 0.7 Ω (Max)
- Avalanche Energy Specified
- Fast Switching
- Simple Drive Requirements
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

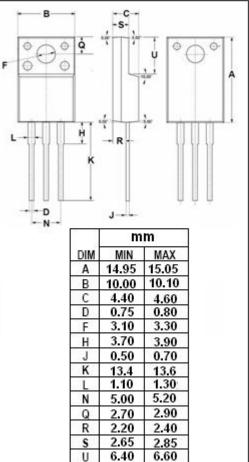
## DESCRITION

• Designed for high efficiency switch mode power supply.

## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER VALUE		UNIT
V <sub>DSS</sub>	Drain-Source Voltage	600	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	uous ±30	
I <sub>D</sub>	Drain Current-Continuous	12	
I <sub>DM</sub>	Drain Current-Single Plused	48	А
Tj	Max. Operating Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55~150	°C





#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.8	°C/W
R <sub>th j-a</sub>	Thermal Resistance, Junction to Ambient	62.5	°C/W

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## **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{C}}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	600		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS}$ = $V_{GS}$ ; $I_D$ = 0.25mA	2	4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 6.0A		0.7	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V; V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 600V; V <sub>GS</sub> = 0		10	μA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 12A; V <sub>GS</sub> = 0		1.4	V



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